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# UNR92AMG

Silicon NPN epitaxial planar type

For digital circuits

#### Features

- Optimum for high-density mounting and downsizing of the equipment
- Contribute to low power consumption

#### Absolute Maximum Ratings $T_a = 25^{\circ}C$

| Parameter                             | Symbol           | Rating      | Unit |  |
|---------------------------------------|------------------|-------------|------|--|
| Collector-base voltage (Emitter open) | V <sub>CBO</sub> | 50          | V    |  |
| Collector-emitter voltage (Base open) | V <sub>CEO</sub> | 50          | V    |  |
| Collector current                     | I <sub>C</sub>   | 80          | mA   |  |
| Total power dissipation               | P <sub>T</sub>   | 125         | mW   |  |
| Junction temperature                  | Tj               | 125         | °C   |  |
| Storage temperature                   | T <sub>stg</sub> | -55 to +125 | °C   |  |



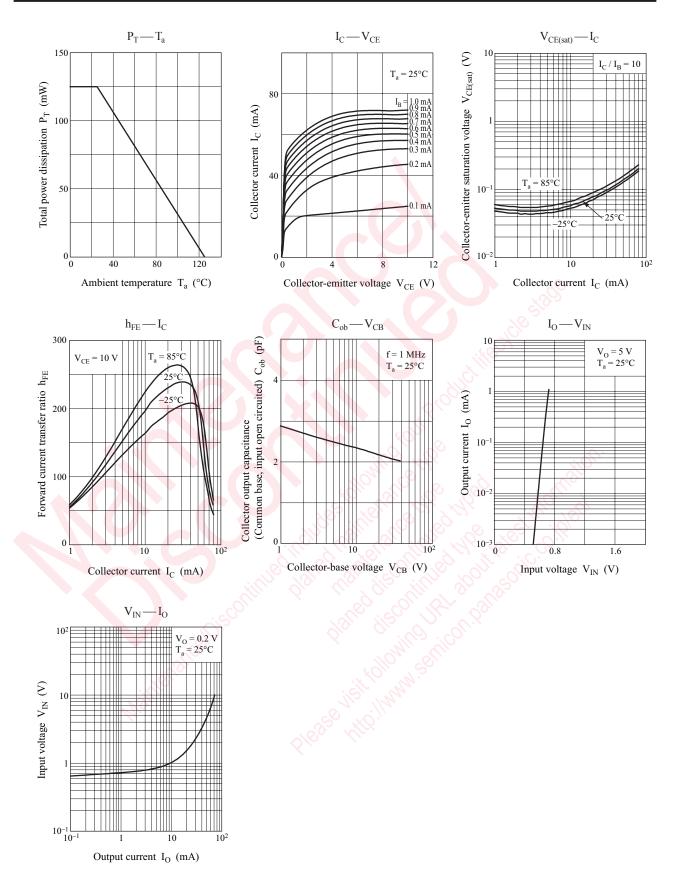
#### Electrical Characteristics $T_a = 25^{\circ}C \pm 3^{\circ}C$

| Parameter                                    | Symbol                          | Conditions   | Min  | Тур   | Max  | Unit |
|--|---------------------------------|--|------|-------|------|------|
| Collector-base voltage (Emitter open)        | V <sub>CBO</sub>                | $I_{\rm C} = 10 \ \mu \text{A}, I_{\rm E} = 0$                                       | 50   |       |      | V    |
| Collector-emitter voltage (Base open)        | V <sub>CEO</sub>                | $I_{\rm C} = 2 \mathrm{mA}, I_{\rm B} = 0$   | 50   |       |      | V    |
| Collector-base cutoff current (Emitter open) | I <sub>CBO</sub>                | $V_{CB} = 50 \text{ V}, I_E = 0$   |      |       | 0.1  | μΑ   |
| Collector-emitter cutoff current (Base open) | I <sub>CEO</sub>                | $V_{\rm CE} = 50 \text{ V}, I_{\rm B} = 0$   |      |       | 0.5  | μΑ   |
| Emitter-base cutoff current (Collector open) | I <sub>EBO</sub>                | $V_{\rm EB} = 6 V, I_{\rm C} = 0$  |      |       | 0.2  | mA   |
| Forward current transfer ratio               | h <sub>FE</sub>                 | $V_{CE} = 10 \text{ V}, I_{C} = 5 \text{ mA}$  | 80   |       |      |      |
| Collector-emitter saturation voltage         | V <sub>CE(sat)</sub>            | $I_{\rm C} = 10 \text{ mA}, I_{\rm B} = 0.3 \text{ mA}$                              |      |       | 0.25 | V    |
| Output voltage high-level                    | V <sub>OH</sub>                 | $V_{CC} = 5 V, V_B = 0.5 V, R_L = 1 k\Omega$   | 4.9  |       |      | V    |
| Output voltage low-level                     | V <sub>OL</sub>                 | $V_{\rm CC} = 5 \text{ V}, V_{\rm B} = 2.5 \text{ V}, R_{\rm L} = 1 \text{ k}\Omega$ |      |       | 0.2  | V    |
| Input resistance                             | R <sub>1</sub>                  |  | -30% | 2.2   | +30% | kΩ   |
| Resistance ratio                             | R <sub>1</sub> / R <sub>2</sub> |  |      | 0.047 |      |      |
| Transition frequency                         | f <sub>T</sub>                  | $V_{CB} = 10 \text{ V}, I_E = -2 \text{ mA}, f = 200 \text{ MHz}$                    |      | 150   |      | MHz  |

Note) Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

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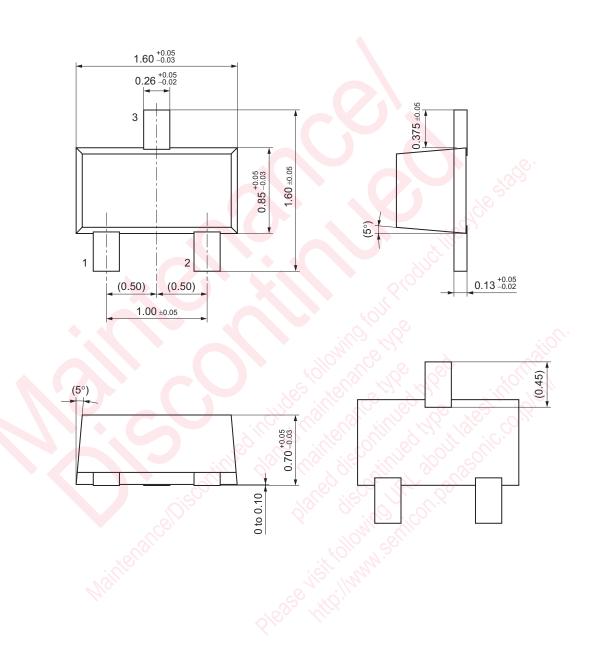
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### SSMini3-F3

Unit: mm



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